TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K15FU

High Speed Switching Applications Analog Switch Applications

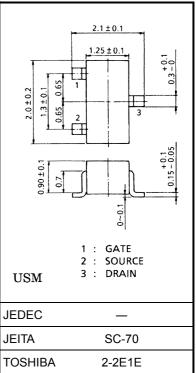
- Small package
- Low on resistance
 - : Ron = 4.0 Ω (max) (@VGS = 4 V)
 - : $R_{on} = 7.0 \ \Omega \ (max) \ (@V_{GS} = 2.5 \ V)$

Maximum Ratings (Ta = 25°C)

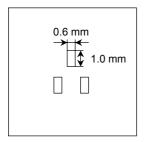
Note: Mounted on FR4 board

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DS}	30	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC	۱ _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25° C)		P _D (Note)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature		T _{stg}	-55~150	°C	

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 0.6 \text{ mm}^2 \times 3)$

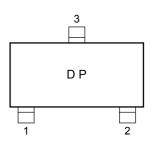


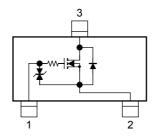
Weight: 0.006 g (typ.)



Marking

Equivalent Circuit





Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

90%

toff

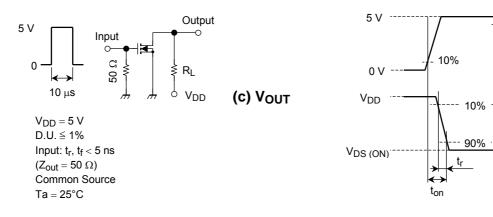
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0$	_		±1	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	30	_		V
Drain cut-off curre	ent	I _{DSS}	$V_{DS} = 30 V, V_{GS} = 0$	_	_	1	μA
Gate threshold vo	oltage	V _{th}	$V_{DS} = 3 V, I_D = 0.1 mA$	0.8	_	1.5	V
Forward transfer	admittance	Y _{fs}	$V_{DS} = 3 V, I_D = 10 mA$	25	_		mS
Drain-source ON resistance		R _{DS (ON)}	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$	_	2.2	4.0	Ω
			$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	4.0	7.0	
Input capacitance		C _{iss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	7.8		pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	3.6		pF
Output capacitance		C _{oss}	$V_{DS} = 3 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	8.8		pF
Switching time	Turn-on time	t _{on}	V _{DD} = 5 V, I _D = 10 mA, V _{GS} = 0~5 V	_	50		ns
	Turn-off time	t _{off}		_	180		

Switching Time Test Circuit

(a) Test circuit

(b) V_{IN}



Precaution

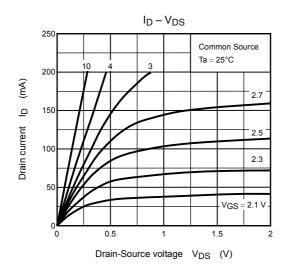
 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 100 μA for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

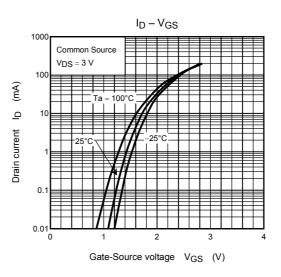
(relationship can be established as follows: $V_{\rm GS}$ (off) < V_{th} < $V_{\rm GS}$ (on))

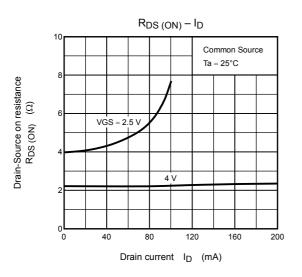
Please take this into consideration for using the device.

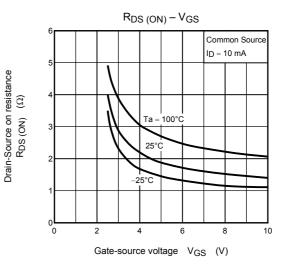
 VGS recommended voltage of 2.5 V or higher to turn on this product.

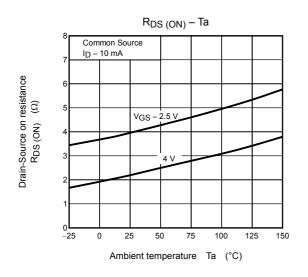
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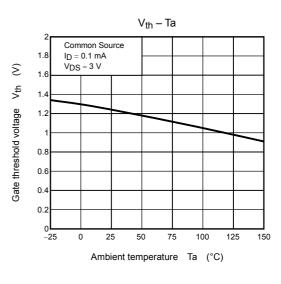




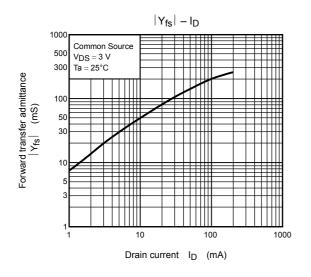


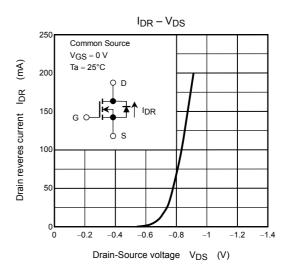


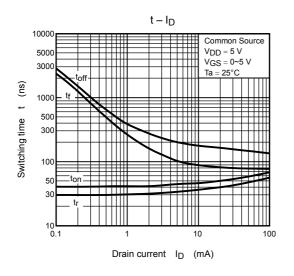


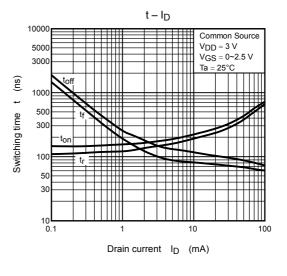


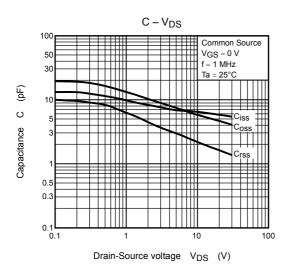
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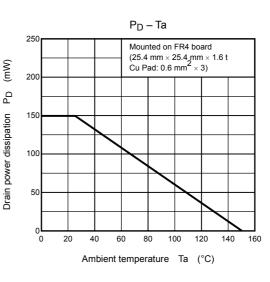












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Handbook" etc.,

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